

OBJECT SENSOR, TRANSISTOR, Sensor Output:Phototransistor, Sensor Mounting:Through Hole, Sensing Distance:1.27mm, Forward Current If:50mA, Reverse Voltage Vr:5V, Collector Emitter Voltage V(br)ceo:30V, Forward Voltage:1.7V

Manufacturers	<u>ON Semiconductor, LLC</u>
Package/Case	DIP-4
Product Type	Optical Sensors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for QRD1113 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

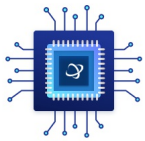
## General Description

### Application

ONSEMI

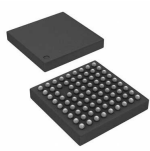


## Related Products



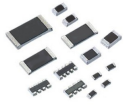
[QRE1114GR](#)

ON Semiconductor, LLC  
ARUSM-313 / REFLECTIVE RECTANGULAR SURFACE MOUNT



[AR0230CSSC12SUEA0-DR](#)

ON Semiconductor, LLC  
IBGA-80



[KDT00030TR](#)

ON Semiconductor, LLC  
SMD



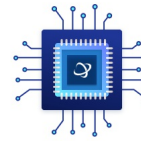
[NOIV1SN1300A-QDC](#)

ON Semiconductor, LLC  
LCC-48



[NOIV2SN2000A-QDC](#)

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[QSB363ZR](#)

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T-3/4



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LCC-48